

## SN74LV8T244 Octal Buffers and Drivers with 3-State Outputs and Logic-Level Shifter

### 1 Features

- Wide operating range of 1.65V to 5.5V
- 5.5V tolerant input pins
- Single-supply voltage translator (refer to *LVxT Enhanced Input Voltage*):
  - Up translation:
    - 1.2V to 1.8V
    - 1.5V to 2.5V
    - 1.8V to 3.3V
    - 3.3V to 5.0V
  - Down translation:
    - 5.0V, 3.3V, 2.5V to 1.8V
    - 5.0V, 3.3V to 2.5V
    - 5.0V to 3.3V
- Up to 150Mbps with 5V or 3.3V  $V_{CC}$
- Supports standard function pinout
- Latch-up performance exceeds 250mA per JESD 17
- Operating ambient temperature: -55°C to +125°C
- Supports defense and aerospace applications:
  - Controlled baseline
  - One assembly and test site
  - One fabrication site
  - Extended product life cycle
  - Product traceability

### 2 Applications

- [Digital signage](#)
- [Controlling an indicator LED](#)
- [Increase the number of outputs on a microcontroller](#)

### 3 Description

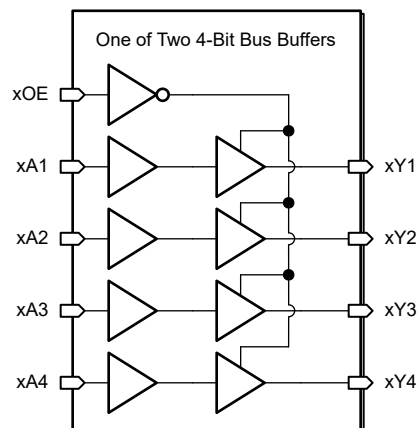
The SN74LV8T244 is an octal buffer with 3-state outputs and Schmitt-trigger inputs. The device is configured into two banks of four drivers, each controlled by an output enable pin.

The input is designed with a reduced threshold circuit to support up translation when the supply voltage is larger than the input voltage. Additionally, the 5V tolerant input pins enable down translation when the input voltage is larger than the supply voltage. The output level is always referenced to the supply voltage ( $V_{CC}$ ) and supports 1.8V, 2.5V, 3.3V, and 5V CMOS levels.

#### Package Information

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE (NOM) <sup>(3)</sup>
SN74LV8T244	RKS (VQFN, 20)	4.5mm × 2.5mm	4.5mm × 2.5mm
SN74LV8T244	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm
SN74LV8T244	DGS (VSSOP, 20)	5.1mm × 4.9mm	5.1mm × 3mm

- (1) For more information, see [Section 13](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) The body size (length × width) is a nominal value and does not include pins.

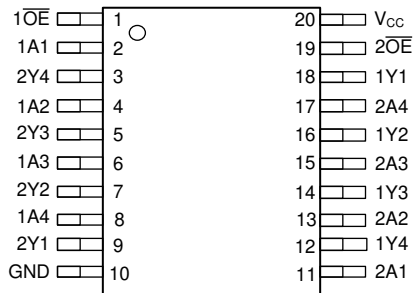


Simplified Logic Diagram (Positive Logic)

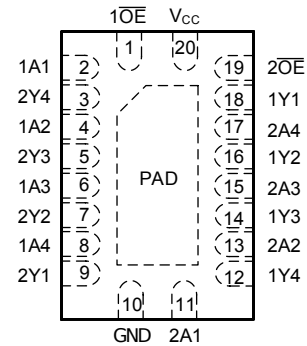
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## 4 Pin Configuration and Functions



**Figure 4-1. PW or DGS Package, 20-Pin TSSOP or VSSOP (Top View)**



**Figure 4-2. SN74LV8T244 RKS Package; 20-Pin TSSOP (Top View)**

**Table 4-1. Pin Functions**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
1OE	1	I	Bank 1, output enable, active low
1A1	2	I	Bank 1, channel 1 input
2Y4	3	O	Bank 2, channel 4 output
1A2	4	I	Bank 1, channel 2 input
2Y3	5	O	Bank 2, channel 3 output
1A3	6	I	Bank 1, channel 3 input
2Y2	7	O	Bank 2, channel 2 output
1A4	8	I	Bank 1, channel 4 input
2Y1	9	O	Bank 2, channel 1 output
GND	10	G	Ground
2A1	11	I	Bank 2, channel 1 input
1Y4	12	O	Bank 1, channel 4 output
2A2	13	I	Bank 2, channel 2 input
1Y3	14	O	Bank 1, channel 3 output
2A3	15	I	Bank 2, channel 3 input
1Y2	16	O	Bank 1, channel 2 output
2A4	17	I	Bank 2, channel 4 input
1Y1	18	O	Bank 1, channel 1 output
2OE	19	I	Bank 2, output enable, active low
V <sub>CC</sub>	20	P	Positive supply
Thermal pad <sup>(2)</sup>			The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power

(2) RKS package only

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	7	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	7	V
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V
V <sub>O</sub>	Output voltage range <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < -0.5 V	-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	±20	mA
I <sub>O</sub>	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>	±25	mA
	Continuous output current through V <sub>CC</sub> or GND		±75	mA
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 5.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

Spec	Description	Condition	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.65	5.5	V
V <sub>I</sub>	Input voltage		0	5.5	V
V <sub>O</sub>	Output voltage		0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 1.65 V to 2 V	1.1		V
		V <sub>CC</sub> = 2.25 V to 2.75 V	1.28		
		V <sub>CC</sub> = 3 V to 3.6 V	1.45		
		V <sub>CC</sub> = 4.5 V to 5.5 V	2		
V <sub>IL</sub>	Low-Level input voltage	V <sub>CC</sub> = 1.65 V to 2 V		0.51	V
		V <sub>CC</sub> = 2.25 V to 2.75 V		0.65	
		V <sub>CC</sub> = 3 V to 3.6 V		0.75	
		V <sub>CC</sub> = 4.5 V to 5.5 V		0.8	
I <sub>O</sub>	Output current	V <sub>CC</sub> = 1.6 V to 2 V		±8	mA
		V <sub>CC</sub> = 2.25 V to 2.75 V		±15	
		V <sub>CC</sub> = 3.3 V to 5.0 V		±25	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 1.6 V to 5.0 V		20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

## 5.4 Thermal Information

PACKAGE	PINS	THERMAL METRIC <sup>(1)</sup>						UNIT
		R <sub>θJA</sub>	R <sub>θJC(top)</sub>	R <sub>θJB</sub>	Ψ <sub>JT</sub>	Ψ <sub>JB</sub>	R <sub>θJC(bot)</sub>	
PW (TSSOP)	20	117.2	58.6	79.1	12.6	78.3	N/A	°C/W
DGS (VSSOP)	20	131.6	69.5	86.7	10.9	85.9	N/A	°C/W
RKS (VQFN)	20	90.4	92.2	63.4	29	63.5	41.3	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

## 5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			-40°C to 125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = -50 uA	1.65 V to 5.5 V	V <sub>CC</sub> -0.1			V <sub>CC</sub> -0.1			V
	I <sub>OH</sub> = -2 mA	1.65 V to 2 V	1.28	1.7 <sup>(1)</sup>		1.21			
	I <sub>OH</sub> = -3 mA	2.25 V to 2.75 V	2	2.4 <sup>(1)</sup>		1.93			
	I <sub>OH</sub> = -5.5 mA	3 V to 3.6 V	2.6	3.08 <sup>(1)</sup>		2.49			
	I <sub>OH</sub> = -8 mA	4.5 V to 5.5 V	4.1	4.65 <sup>(1)</sup>		3.95			
V <sub>OL</sub>	I <sub>OL</sub> = 50 uA	1.65 V to 5.5 V			0.1			0.1	V
	I <sub>OL</sub> = 2 mA	1.65 V to 2 V		0.1 <sup>(1)</sup>	0.2			0.25	
	I <sub>OL</sub> = 3 mA	2.25 V to 2.75 V		0.15 <sup>(1)</sup>	0.17			0.2	
	I <sub>OL</sub> = 5.5 mA	3 V to 3.6 V		0.2 <sup>(1)</sup>	0.23			0.25	
	I <sub>OL</sub> = 8 mA	4.5 V to 5.5 V		0.3 <sup>(1)</sup>	0.3			0.35	
I <sub>I</sub>	V <sub>I</sub> = 0 V or V <sub>CC</sub>	0 V to 5.5 V				±0.1		±1	μA
I <sub>CC</sub>	V <sub>I</sub> = 0 V or V <sub>CC</sub> , I <sub>O</sub> = 0; open on loading	1.65 V to 5.5 V				2		20	μA
ΔI <sub>CC</sub>	One input at 0.3 V or 3.4 V, other inputs at 0 or V <sub>CC</sub> , I <sub>O</sub> = 0	5.5 V				1.35		1.5	mA
	One input at 0.3 V or 1.1 V, other inputs at 0 or V <sub>CC</sub> , I <sub>O</sub> = 0	1.8 V				10		20	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND and V <sub>CC</sub> = 5.5 V	5.5 V				±0.25		±2.5	μA
C <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V			4	10		10	pF
C <sub>O</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5 V			5				pF
C <sub>PD</sub>	No load, F = 1MHz	5 V			17				pF

(1) Typical value at nearest nominal voltage (1.8 V, 2.5 V, 3.3 V, and 5 V)

## 5.6 Switching Characteristics

Over operating free-air temperature range; typical values measured at T<sub>A</sub> = 25°C (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	V <sub>CC</sub>	T <sub>A</sub> = 25°C			-40°C to 125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
t <sub>PLH</sub>	A	Y	C <sub>L</sub> = 15pF	1.8V	5.3	12.4	4.8	13.5	ns		
t <sub>PHL</sub>	A	Y	C <sub>L</sub> = 15pF	1.8V	6.6	15.9	5.8	17.4	ns		
t <sub>PZH</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.8V	8.3	18.4	7.2	20.6	ns		
t <sub>PZL</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.8V	7.2	17.1	6.4	18.7	ns		
t <sub>PHZ</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.8V	7.1	13.6	6.3	15.4	ns		
t <sub>PLZ</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.8V	6.9	11.9	6.3	13.2	ns		

## 5.6 Switching Characteristics (continued)

Over operating free-air temperature range; typical values measured at  $T_A = 25^\circ\text{C}$  (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$V_{CC}$	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
$t_{PLH}$	A	Y	$C_L = 50\text{pF}$	1.8V	7.3	16.7	6.5	18.3	ns		
$t_{PHL}$					8.3	19.6	7.5	21.8	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	1.8V	10.6	23	9.5	25.7	ns		
$t_{PZL}$					9.2	21.2	8.3	23.4	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	1.8V	12.9	20.8	12.1	22.8	ns		
$t_{PLZ}$					12.6	19.3	12.1	20.6	ns		
$t_{sk(o)}$			$C_L = 50\text{pF}$	1.8V		0.5		0.5	ns		
$t_{PLH}$	A	Y	$C_L = 15\text{pF}$	2.5V	3.9	7.7	3.4	8.8	ns		
$t_{PHL}$					4.8	9.8	4.3	11.3	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	2.5V	6.1	11.6	5.3	13.2	ns		
$t_{PZL}$					5.2	10.6	4.6	12.1	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	2.5V	5	8.6	4.4	9.9	ns		
$t_{PLZ}$					5.1	8	4.7	9	ns		
$t_{PLH}$	A	Y	$C_L = 50\text{pF}$	2.5V	5.3	10.6	4.7	12	ns		
$t_{PHL}$					6.2	12.5	5.6	14.3	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	2.5V	8	14.9	7.1	16.9	ns		
$t_{PZL}$					6.9	13.5	6.2	15.4	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	2.5V	8.8	13.5	8.1	15	ns		
$t_{PLZ}$					9	12.9	8.6	14	ns		
$t_{sk(o)}$			$C_L = 50\text{pF}$	2.5V		0.3		0.4	ns		
$t_{PLH}$	A	Y	$C_L = 15\text{pF}$	3.3V	3.4	6.4	3	7.3	ns		
$t_{PHL}$					4.3	8.1	3.7	9.4	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	3.3V	5.4	9.5	4.6	11	ns		
$t_{PZL}$					4.5	8.7	4	9.9	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	3.3V	3.9	6.9	3.3	8.1	ns		
$t_{PLZ}$					4.4	6.8	4.1	7.6	ns		
$t_{PLH}$	A	Y	$C_L = 50\text{pF}$	3.3V	4.6	8.8	4	10.1	ns		
$t_{PHL}$					5.5	10.4	4.9	11.9	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	3.3V	7.1	12.4	6.3	14.1	ns		
$t_{PZL}$					6.1	11.3	5.6	12.9	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	3.3V	7	10.7	6.5	12	ns		
$t_{PLZ}$					7.7	10.8	7.3	11.6	ns		
$t_{sk(o)}$			$C_L = 50\text{pF}$	3.3V		0.3		0.4	ns		
$t_{PLH}$	A	Y	$C_L = 15\text{pF}$	5V	3.1	5.4	2.9	6.1	ns		
$t_{PHL}$					3.1	5.5	2.7	6.4	ns		
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	5V	4	6.7	3.5	7.8	ns		
$t_{PZL}$					3.3	5.9	2.9	6.9	ns		
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 15\text{pF}$	5V	3.1	5.1	2.8	6	ns		
$t_{PLZ}$					4.3	6	4.1	6.6	ns		
$t_{PLH}$	A	Y	$C_L = 50\text{pF}$	5V	4.1	7.2	3.7	8.1	ns		
$t_{PHL}$					4.2	7.2	3.7	8.4	ns		

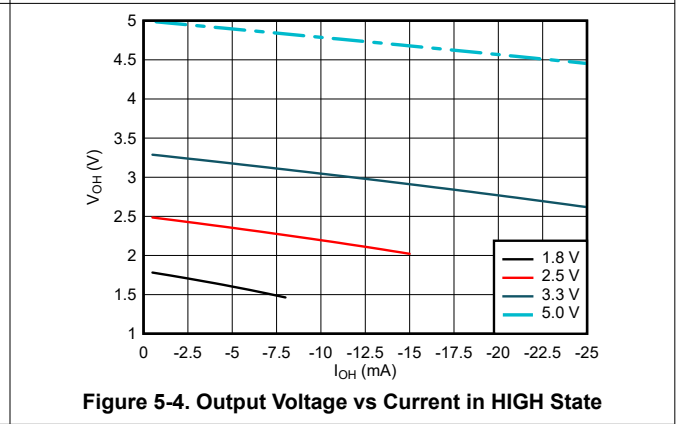
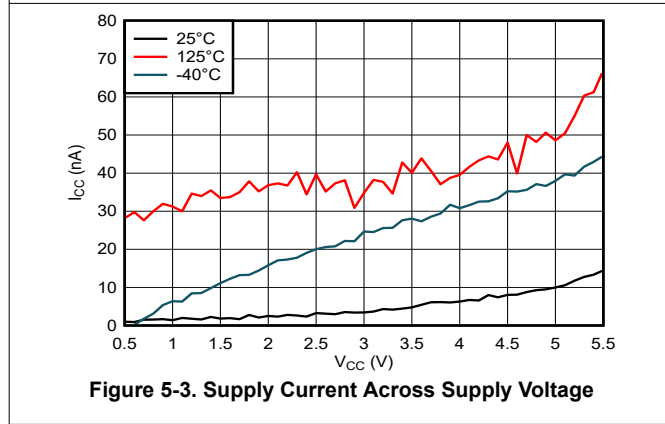
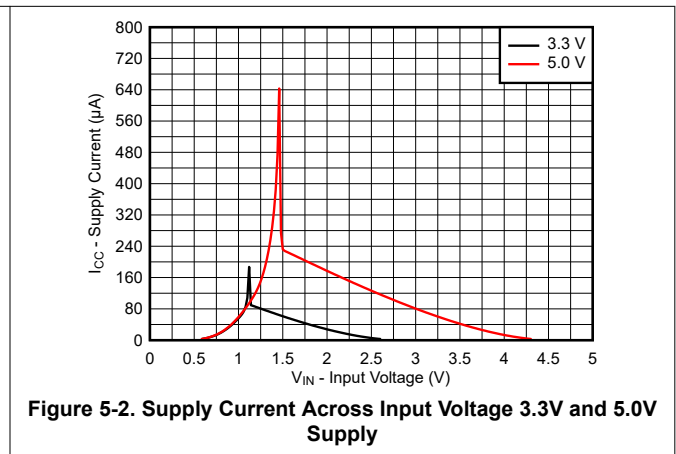
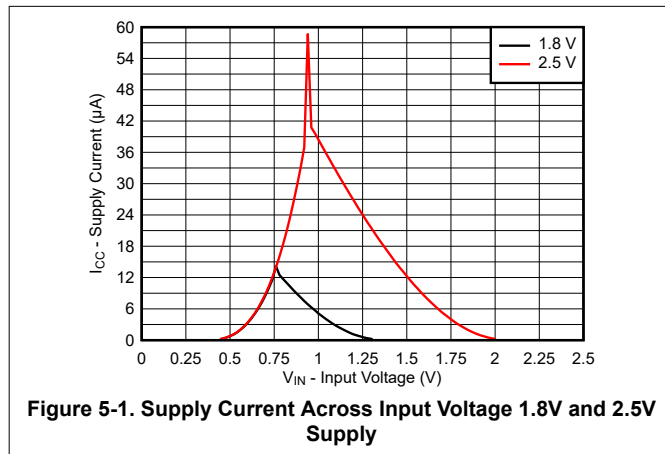
### 5.6 Switching Characteristics (continued)

Over operating free-air temperature range; typical values measured at  $T_A = 25^\circ\text{C}$  (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$V_{CC}$	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
$t_{PZH}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	5V	5.4	9		4.7	10.3		ns
$t_{PZL}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	5V	4.6	8		4.1	9.2		ns
$t_{PHZ}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	5V	4.9	7.3		4.6	8.3		ns
$t_{PLZ}$	$\overline{OE}$	Y	$C_L = 50\text{pF}$	5V	6.2	8.5		6	9.1		ns
$t_{sk(o)}$			$C_L = 50\text{pF}$	5V			0.4		0.4		ns

### 5.7 Typical Characteristics

$T_A = 25^\circ\text{C}$  (unless otherwise noted)



## 5.7 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$  (unless otherwise noted)

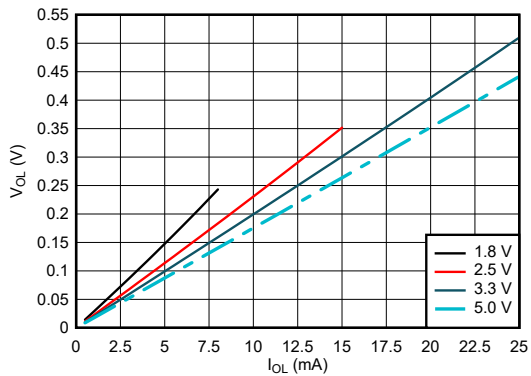


Figure 5-5. Output Voltage vs Current in LOW State

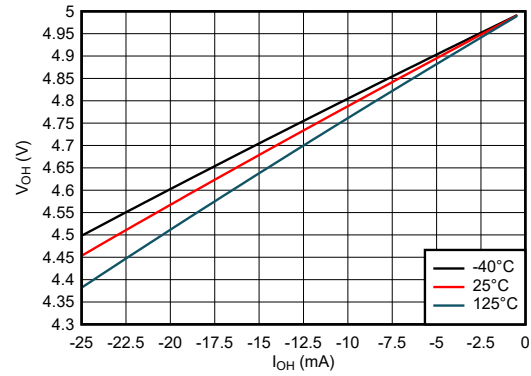


Figure 5-6. Output Voltage vs Current in HIGH State; 5V Supply

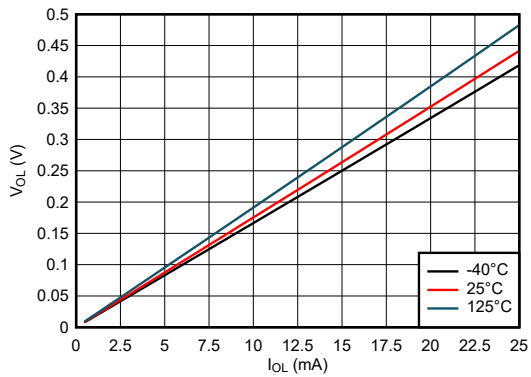


Figure 5-7. Output Voltage vs Current in LOW State; 5V Supply

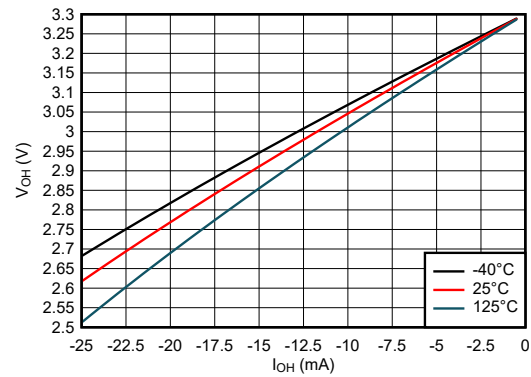


Figure 5-8. Output Voltage vs Current in HIGH State; 3.3V Supply

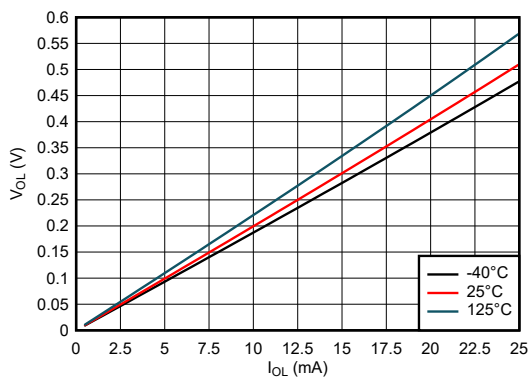


Figure 5-9. Output Voltage vs Current in LOW State; 3.3V Supply

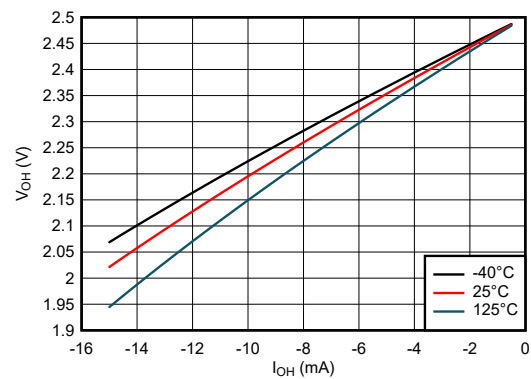
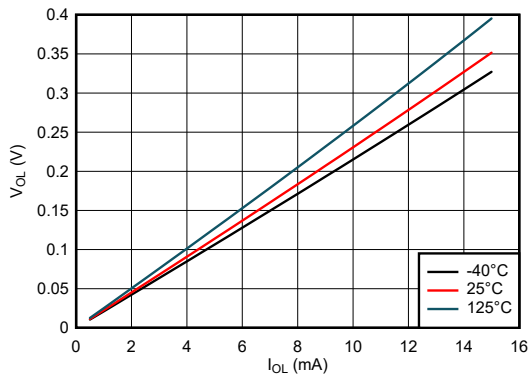


Figure 5-10. Output Voltage vs Current in HIGH State; 2.5V Supply

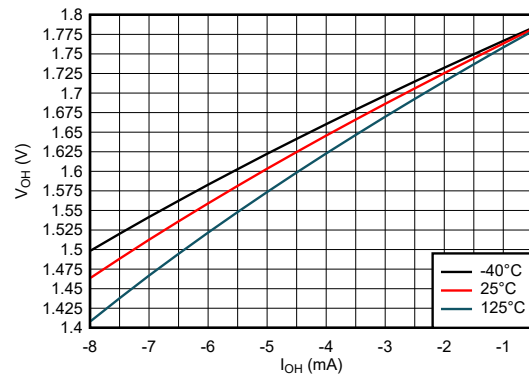


## 5.7 Typical Characteristics (continued)

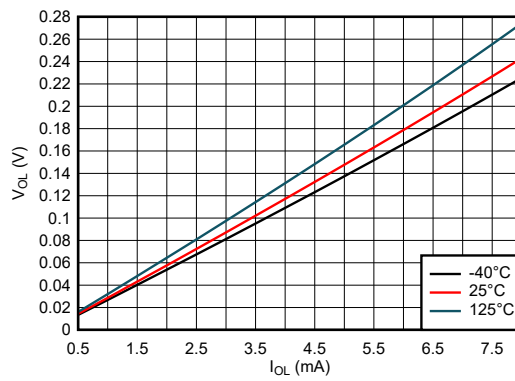
$T_A = 25^\circ\text{C}$  (unless otherwise noted)



**Figure 5-11. Output Voltage vs Current in LOW State; 2.5V Supply**



**Figure 5-12. Output Voltage vs Current in HIGH State; 1.8V Supply**



**Figure 5-13. Output Voltage vs Current in LOW State; 1.8V Supply**

## 5.8 Typical Characteristics

$T_A = 25^\circ\text{C}$  (unless otherwise noted)

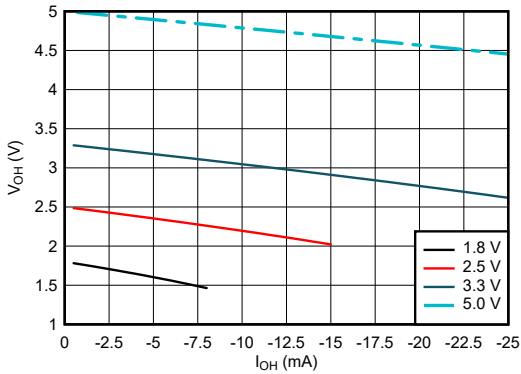


Figure 5-14. Output Voltage vs Current in HIGH State

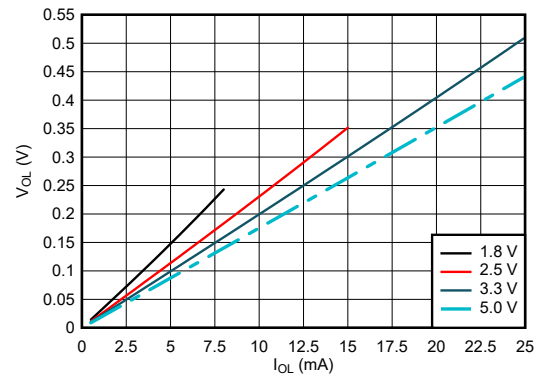


Figure 5-15. Output Voltage vs Current in LOW State

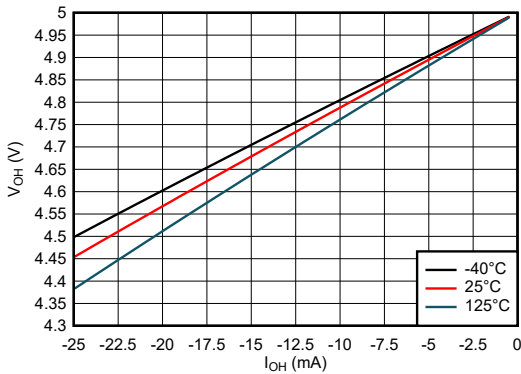


Figure 5-16. Output Voltage vs Current in HIGH State; 5V Supply

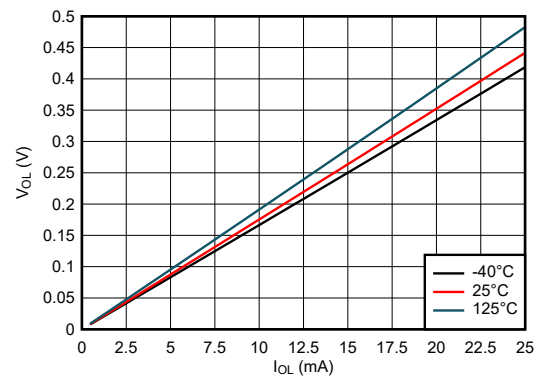


Figure 5-17. Output Voltage vs Current in LOW State; 5V Supply

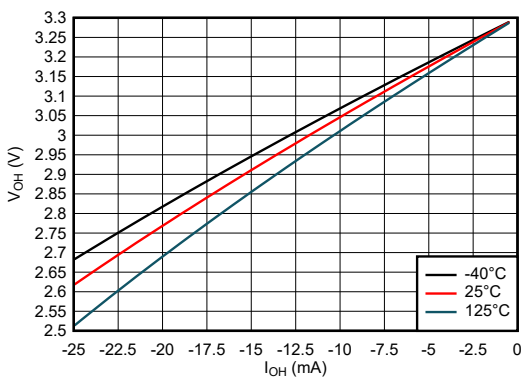


Figure 5-18. Output Voltage vs Current in HIGH State; 3.3V Supply

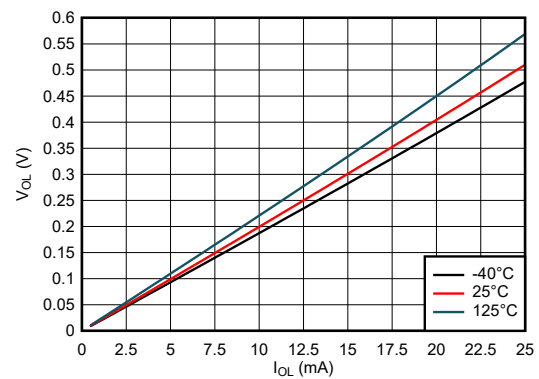
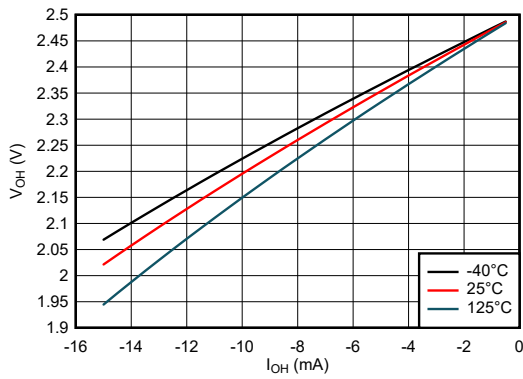


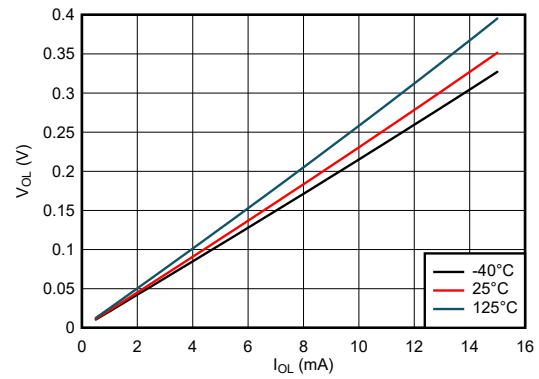
Figure 5-19. Output Voltage vs Current in LOW State; 3.3V Supply

### 5.8 Typical Characteristics (continued)

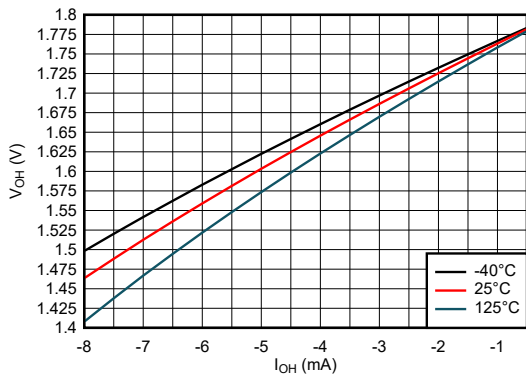
T<sub>A</sub> = 25°C (unless otherwise noted)



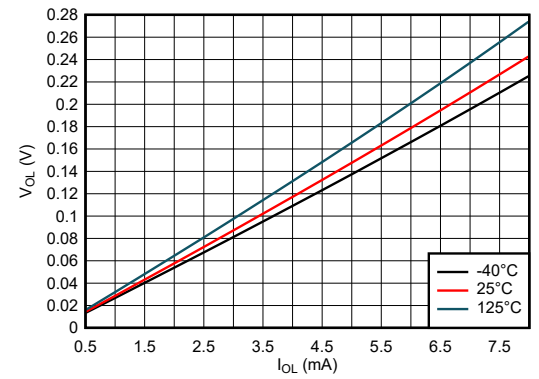
**Figure 5-20. Output Voltage vs Current in HIGH State; 2.5V Supply**



**Figure 5-21. Output Voltage vs Current in LOW State; 2.5V Supply**



**Figure 5-22. Output Voltage vs Current in HIGH State; 1.8V Supply**



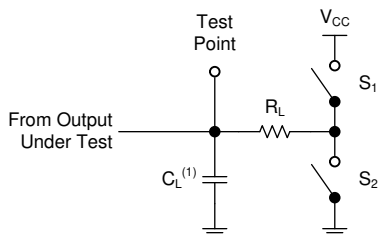
**Figure 5-23. Output Voltage vs Current in LOW State; 1.8V Supply**

## 6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1MHz,  $Z_O = 50\Omega$ ,  $t_f < 2.5\text{ns}$ .

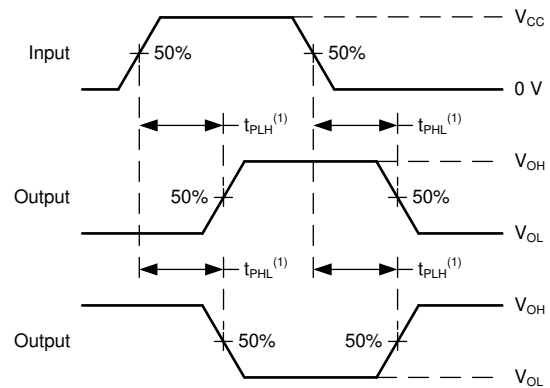
The outputs are measured individually with one input transition per measurement.

TEST	S1	S2	$R_L$	$C_L$	$\Delta V$	$V_{CC}$
$t_{PLH}$ , $t_{PHL}$	OPEN	OPEN	—	15pF, 50pF	—	ALL
$t_{PLZ}$ , $t_{PZL}$	CLOSED	OPEN	1k $\Omega$	15pF, 50pF	0.15V	$\leq 2.5\text{V}$
$t_{PHZ}$ , $t_{PZH}$	OPEN	CLOSED	1k $\Omega$	15pF, 50pF	0.15V	$\leq 2.5\text{V}$
$t_{PLZ}$ , $t_{PZL}$	CLOSED	OPEN	1k $\Omega$	15pF, 50pF	0.3V	$> 2.5\text{V}$
$t_{PHZ}$ , $t_{PZH}$	OPEN	CLOSED	1k $\Omega$	15pF, 50pF	0.3V	$> 2.5\text{V}$



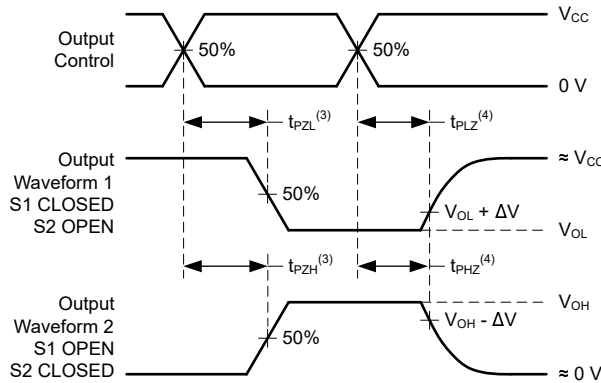
(1)  $C_L$  includes probe and test-fixture capacitance.

**Figure 6-1. Load Circuit for 3-State Outputs**



(1) The greater between  $t_{PLH}$  and  $t_{PHL}$  is the same as  $t_{pd}$ .

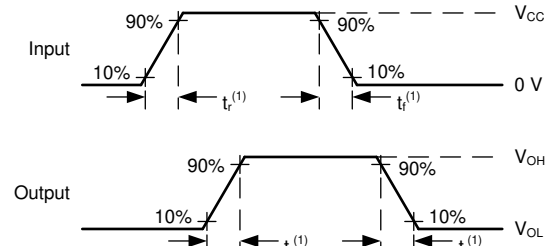
**Figure 6-2. Voltage Waveforms Propagation Delays**



(3) The greater between  $t_{PZL}$  and  $t_{PZH}$  is the same as  $t_{en}$ .

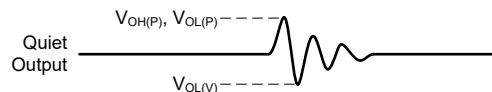
(4) The greater between  $t_{PLZ}$  and  $t_{PHZ}$  is the same as  $t_{dis}$ .

**Figure 6-3. Voltage Waveforms Propagation Delays**



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

**Figure 6-4. Voltage Waveforms, Input and Output Transition Times**



Noise values measured with all other outputs simultaneously switching.

**Figure 6-5. Voltage Waveforms, Noise**

## 7 Detailed Description

### 7.1 Overview

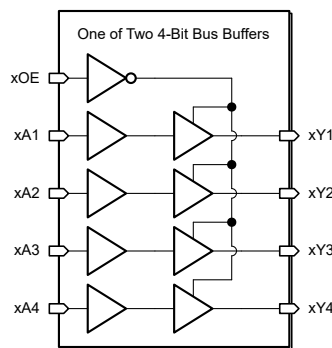
The SN74LV8T244 contains 8 individual high speed CMOS buffers with 3-state outputs.

Each buffer performs the boolean logic function  $xY_n = xA_n$ , with  $x$  being the bank number and  $n$  being the channel number.

Each output enable ( $x\overline{OE}$ ) controls four buffers. When the  $x\overline{OE}$  pin is in the low state, the outputs of all buffers in the bank  $x$  are enabled. When the  $x\overline{OE}$  pin is in the high state, the outputs of all buffers in the bank  $x$  are disabled. All disabled output are placed into the high-impedance state.

To put the device in the high-impedance state during power up or power down, tie both  $\overline{OE}$  pins to  $V_{CC}$  through a pull-up resistor; the current sinking capability of the driver determines the minimum value of the resistor, and the leakage of the pin as defined in the *Electrical Characteristics* table.

### 7.2 Functional Block Diagram



## 8 Feature Description

### 8.1 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device can drive larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance state, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a 10k $\Omega$  resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

### 8.2 LVxT Enhanced Input Voltage

The SN74LV8T244 belongs to TI's LVxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5V levels to support down-translation. For proper functionality, input signals must remain at or above the specified  $V_{IH(MIN)}$  level for a HIGH input state, and at or below the specified  $V_{IL(MAX)}$  for a LOW input state. Figure 8-1 shows the typical  $V_{IH}$  and  $V_{IL}$  levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law ( $R = V \div I$ ).

Input signals must transition between valid logic states quickly, as defined by the input transition rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the [Implications of Slow or Floating CMOS Inputs](#) application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at a valid high or low voltage level. If a system will not be actively driving an input at all times, then a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a 10kΩ resistor is recommended and will typically meet all requirements.

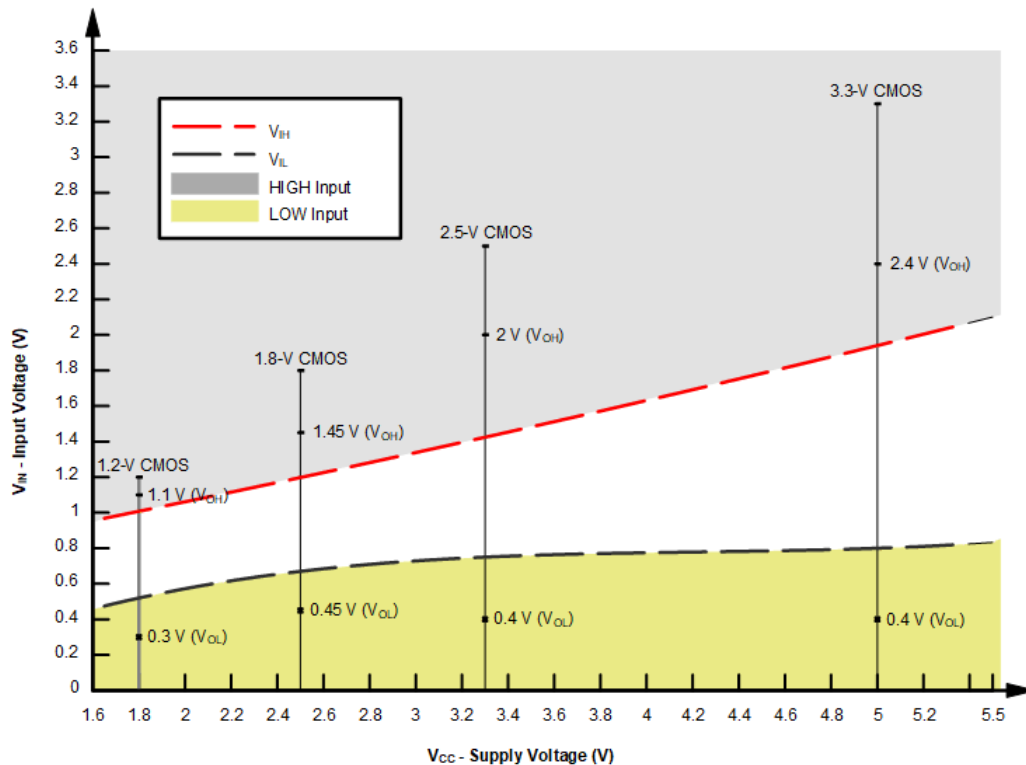


Figure 8-1. LVxT Input Voltage Levels

### 8.3 Clamp Diode Structure

As [Figure 8-2](#) shows, the outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only.

**CAUTION**

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

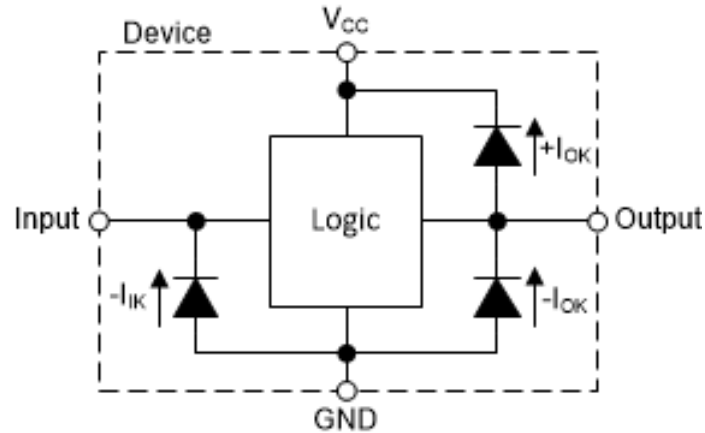


Figure 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

## 9 Device Functional Modes

Table 9-1 lists the functional modes of the SN74LV8T244.

Table 9-1. Function Table

INPUTS <sup>(1)</sup>		OUTPUTS
$\overline{OE}$	A	Y
L	L	L
L	H	H
H	X	Z

(1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High-Impedance State

## 10 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 10.1 Application Information

The SN74LV8T244 can be used to drive signals over relatively long traces or transmission lines. A series damping resistor placed in series with the transmitter's output can be used to reduce ringing caused by impedance mismatches between the driver, transmission line, and receiver. The figure in the *Application Curve* section shows the received signal with three separate resistor values. Just a small amount of resistance can make a significant impact on signal integrity in this type of application.

### 10.2 Typical Application

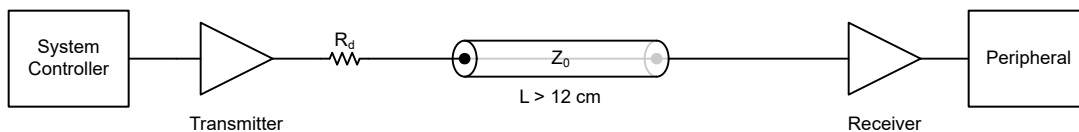


Figure 10-1. Typical Application Block Diagram

#### 10.2.1 Design Requirements

##### 10.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics*.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV8T244 plus the maximum static supply current,  $I_{CC}$ , listed in the *Electrical Characteristics* and any transient current required for switching. The logic device can only source as much current as is provided by the positive supply source. Ensure the maximum total current through  $V_{CC}$  listed in the *Absolute Maximum Ratings* is not exceeded.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV8T244 plus the maximum supply current,  $I_{CC}$ , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current as can be sunk into its ground connection. Ensure the maximum total current through GND listed in the *Absolute Maximum Ratings* is not exceeded.

The SN74LV8T244 can drive a load with a total capacitance less than or equal to 50pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50pF.

The SN74LV8T244 can drive a load with total resistance described by  $R_L \geq V_O / I_O$ , with the output voltage and current defined in the *Electrical Characteristics* table with  $V_{OH}$  and  $V_{OL}$ . When outputting in the high state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the  $V_{CC}$  pin.

Total power consumption can be calculated using the information provided in [CMOS Power Consumption and Cpd Calculation](#).

Thermal increase can be calculated using the information provided in [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices](#).



**CAUTION**

The maximum junction temperature,  $T_{J(max)}$  listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

**10.2.1.2 Input Considerations**

Input signals must cross  $V_{IL(max)}$  to be considered a logic LOW, and  $V_{IH(min)}$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74LV8T244, as specified in the *Electrical Characteristics*, and the desired input transition rate. A 10k $\Omega$  resistor value is often used due to these factors.

The SN74LV8T244 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

**10.2.1.3 Output Considerations**

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OL}$  specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to  $V_{CC}$  or ground.

Refer to *Feature Description* section for additional information regarding the outputs for this device.

**10.2.2 Detailed Design Procedure**

1. Add a decoupling capacitor from  $V_{CC}$  to GND. The capacitor needs to be placed physically close to the device and electrically close to both the  $V_{CC}$  and GND pins. An example layout is shown in the *Layout* section.
2. Ensure the capacitive load at the output is  $\leq 50$ pF. This is not a hard limit; by design, however, it will optimize performance. This can be accomplished by providing short, appropriately sized traces from the SN74LV8T244 to one or more of the receiving devices.
3. Ensure the resistive load at the output is larger than  $(V_{CC} / I_{O(max)})\Omega$ . Doing this will prevent the maximum output current from the *Absolute Maximum Ratings* from being violated. Most CMOS inputs have a resistive load measured in M $\Omega$ ; much larger than the minimum calculated previously.
4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, [CMOS Power Consumption and Cpd Calculation](#).

### 10.2.3 Application Curves

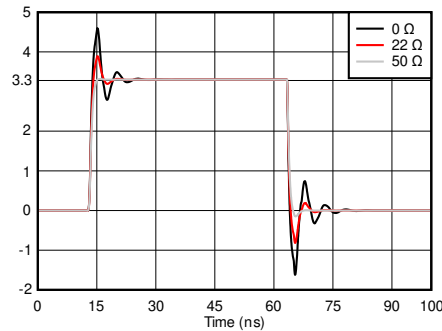


Figure 10-2. Simulated Signal Integrity at the Receiver With Different Damping Resistor ( $R_d$ ) Values

### 10.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A  $0.1\mu\text{F}$  capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The  $0.1\mu\text{F}$  and  $1\mu\text{F}$  capacitors are commonly used in parallel. As shown in the following layout example, install the bypass capacitor as close to the power terminal as possible for best results.

### 10.4 Layout

#### 10.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 10.4.2 Layout Example

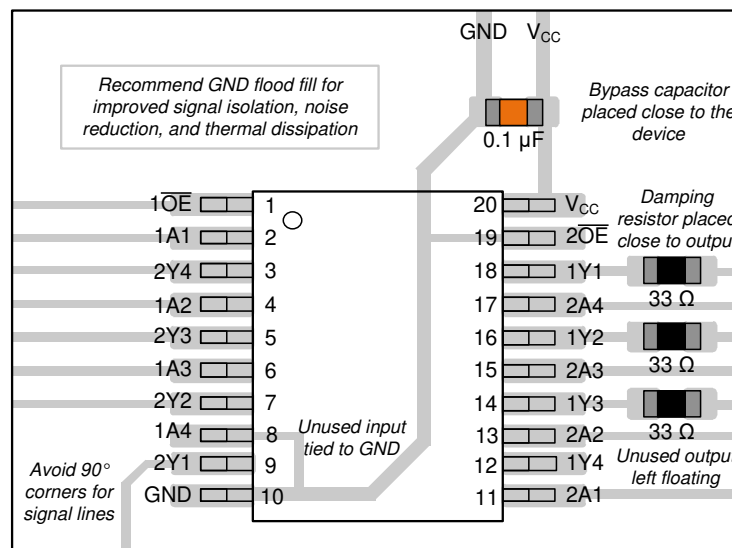


Figure 10-3. Example Layout for the SN74LV8T244 in TSSOP

## 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [CMOS Power Consumption and  \$C\_{pd}\$  Calculation application report](#)
- Texas Instruments, [Designing With Logic application report](#)
- Texas Instruments, [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices application report](#)

### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.  
All trademarks are the property of their respective owners.

### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 12 Revision History

DATE	REVISION	NOTES
June 2025	*	Initial Release

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">SN74LV8T244DGSR</a>	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8T244
<a href="#">SN74LV8T244PWR</a>	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T244
<a href="#">SN74LV8T244RKSR</a>	Active	Production	VQFN (RKS)   20	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T244

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF SN74LV8T244 :**

- Automotive : [SN74LV8T244-Q1](#)

- Enhanced Product : [SN74LV8T244-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV8T244DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74LV8T244PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV8T244RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV8T244DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74LV8T244PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74LV8T244RKS	VQFN	RKS	20	3000	210.0	185.0	35.0

PW0020A



# PACKAGE OUTLINE

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220206/A 02/2017

### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153.



# EXAMPLE BOARD LAYOUT

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220206/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

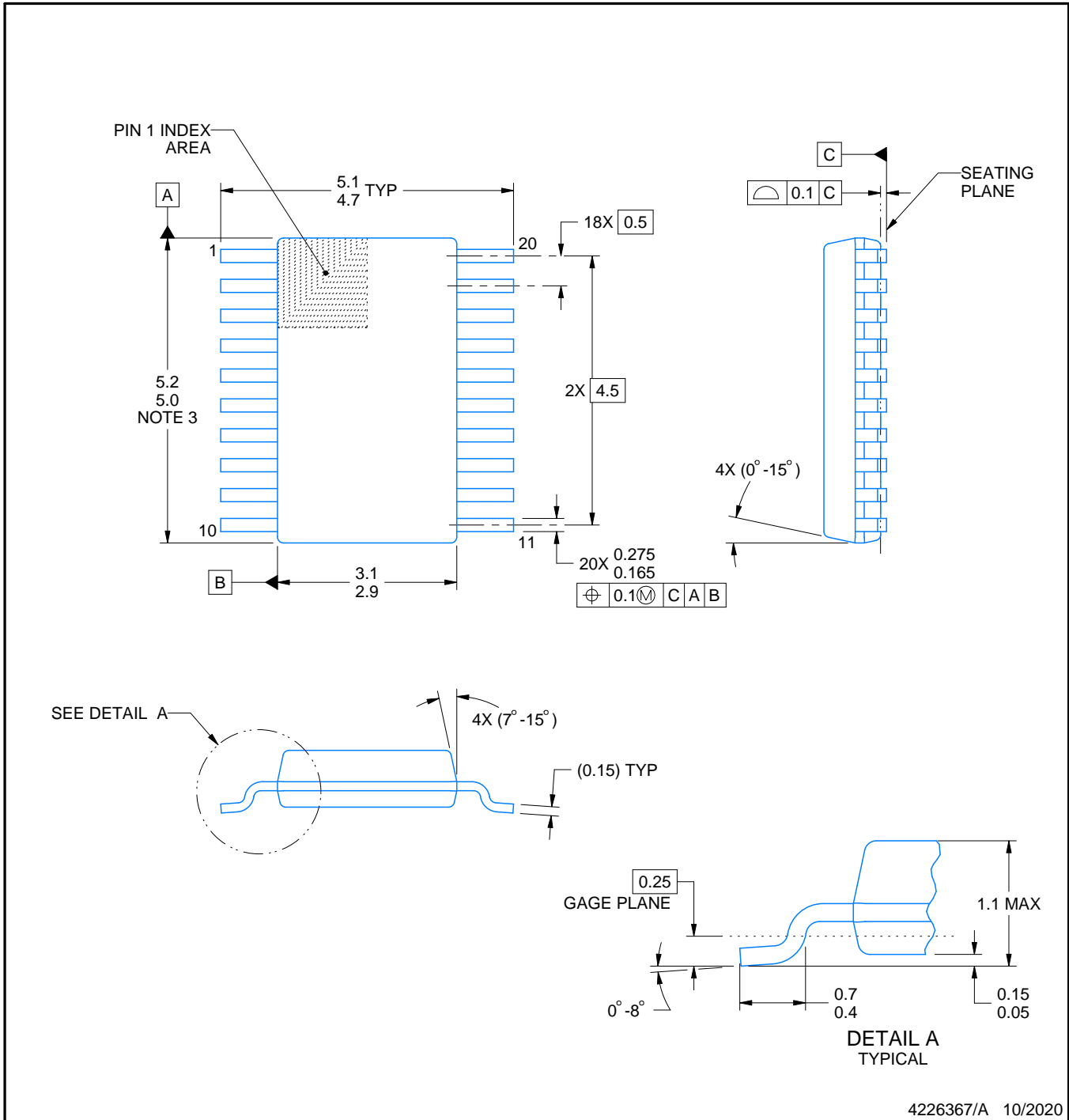
# DGS0020A



# PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4226367/A 10/2020

**NOTES:**

PowerPAD is a trademark of Texas Instruments.

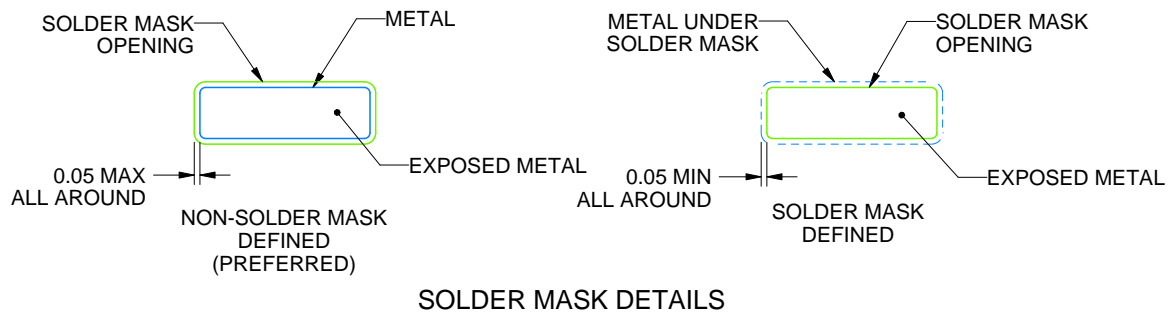
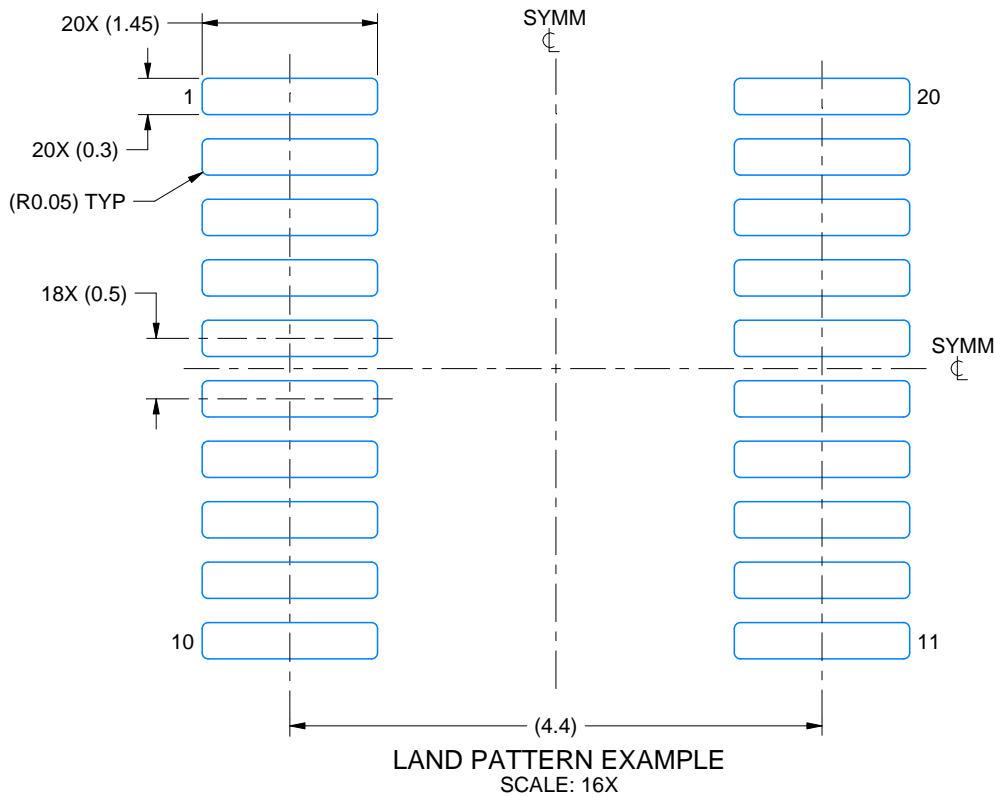
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. No JEDEC registration as of September 2020.
5. Features may differ or may not be present.

# EXAMPLE BOARD LAYOUT

DGS0020A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4226367/A 10/2020

NOTES: (continued)

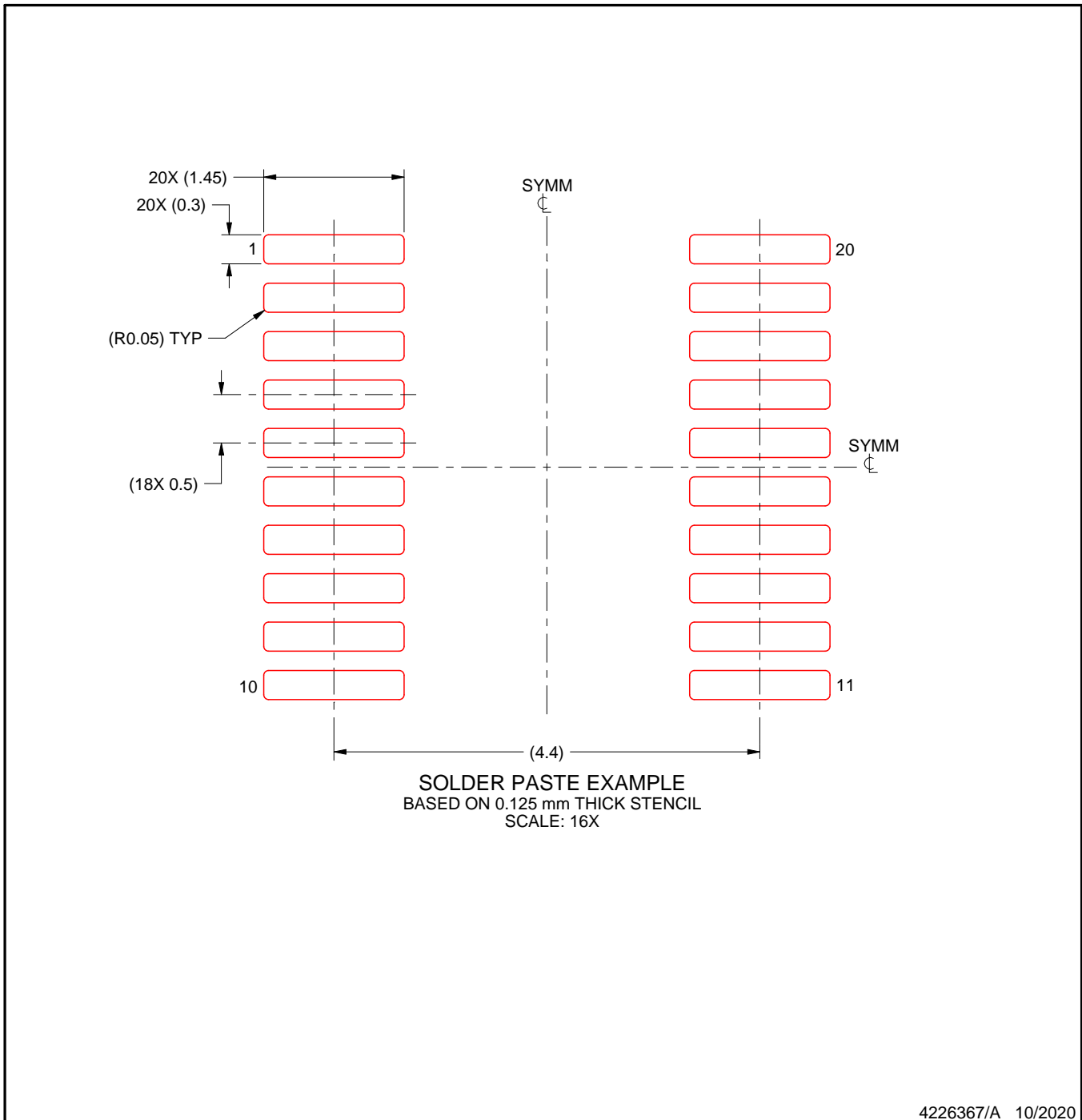
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 ([www.ti.com/lit/slma002](http://www.ti.com/lit/slma002)) and SLMA004 ([www.ti.com/lit/slma004](http://www.ti.com/lit/slma004)).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

DGS0020A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

## GENERIC PACKAGE VIEW

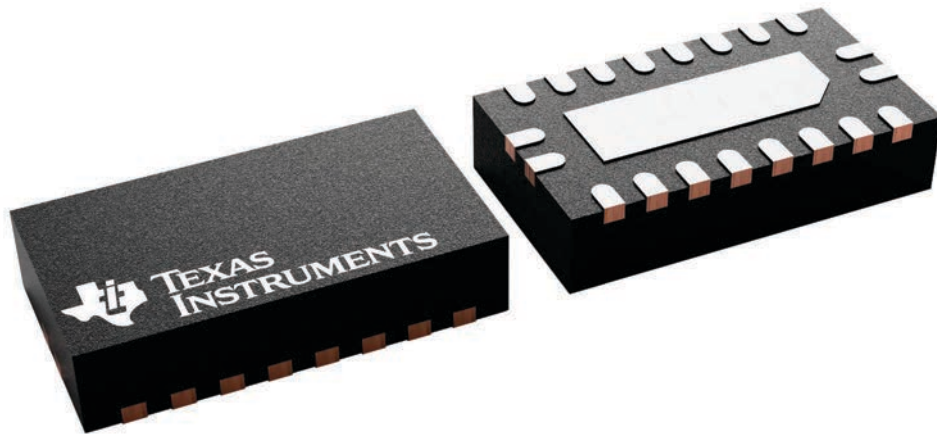
**RKS 20**

**VQFN - 1 mm max height**

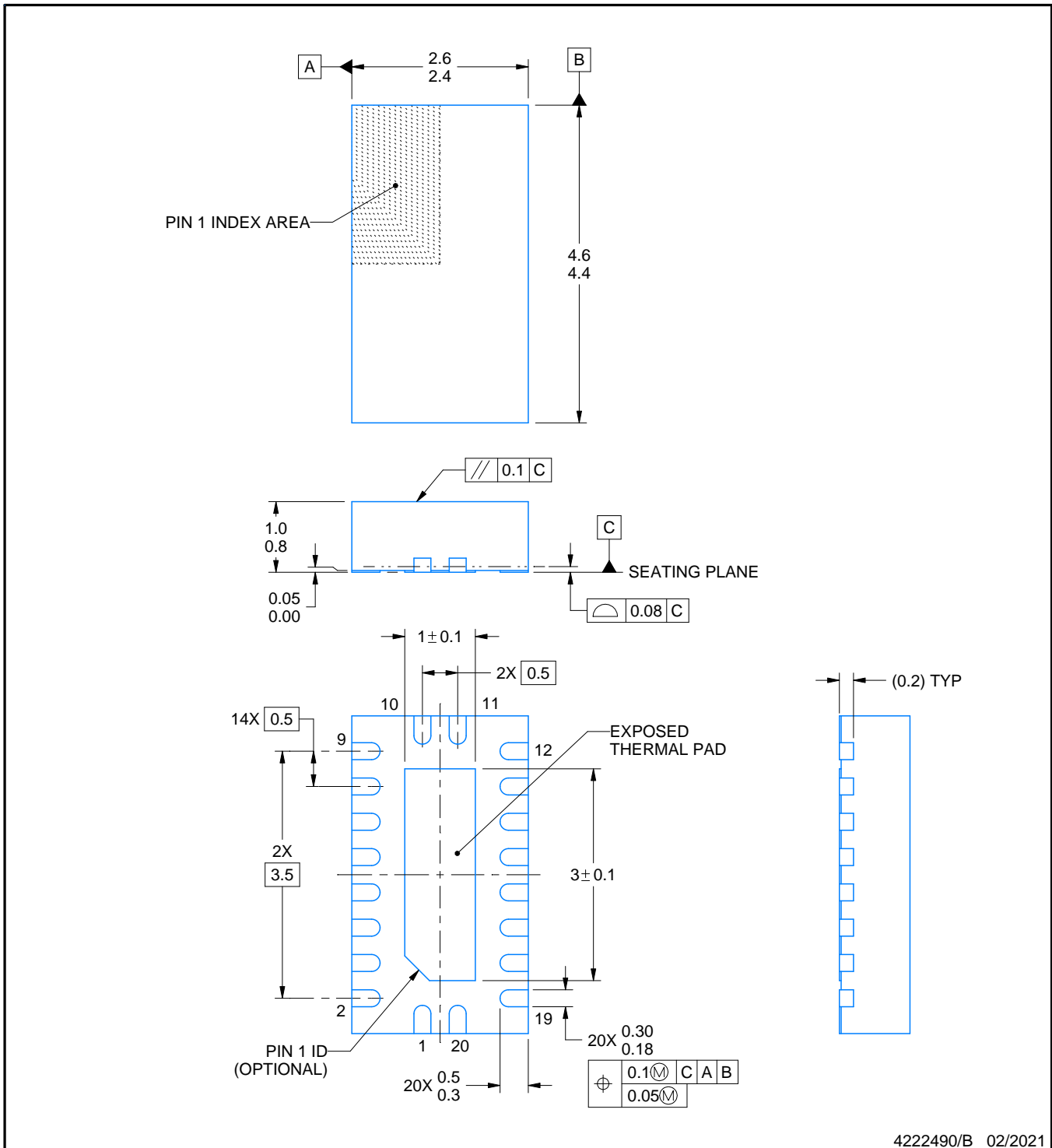
2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4226872/A



NOTES:

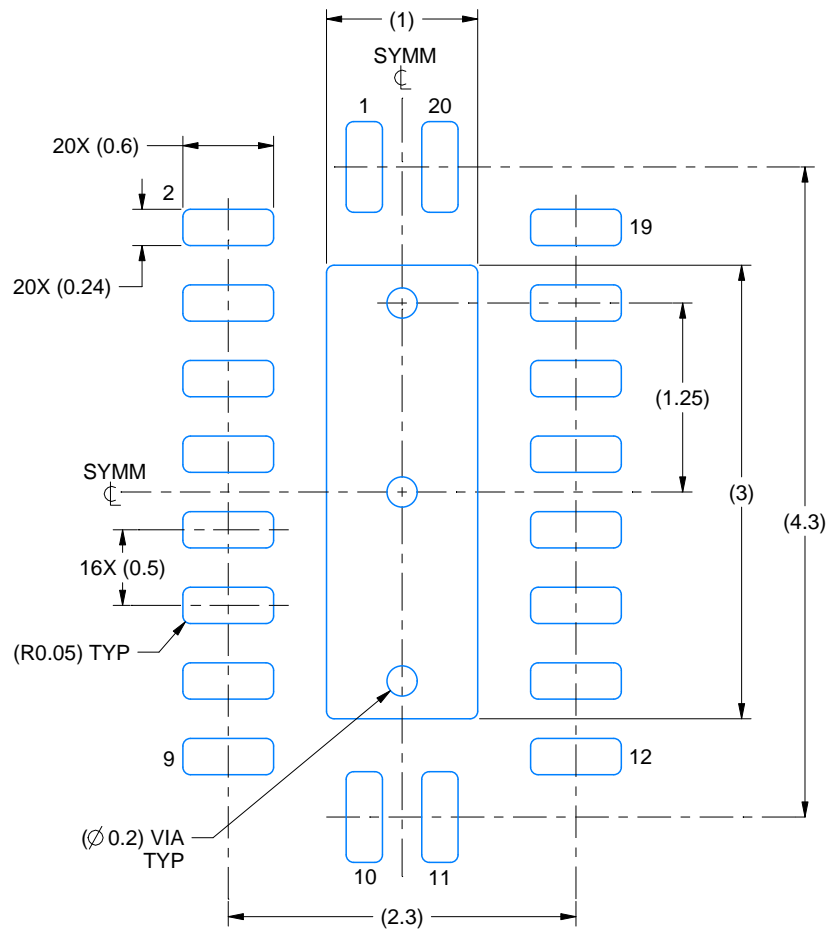
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

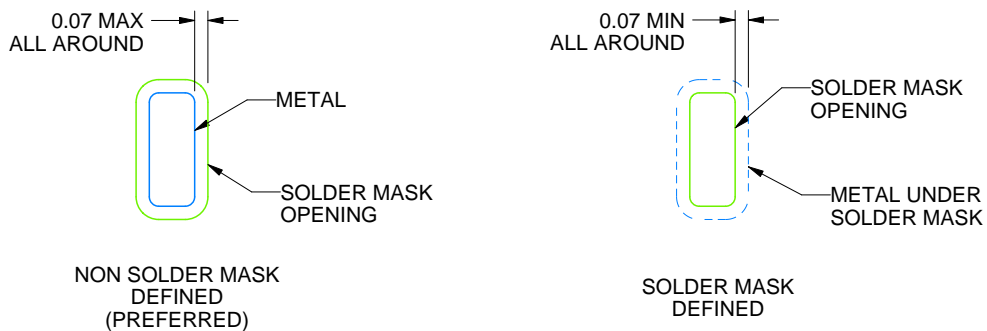
RKS0020A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:20X



SOLDER MASK DETAILS

4222490/B 02/2021

NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
- Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

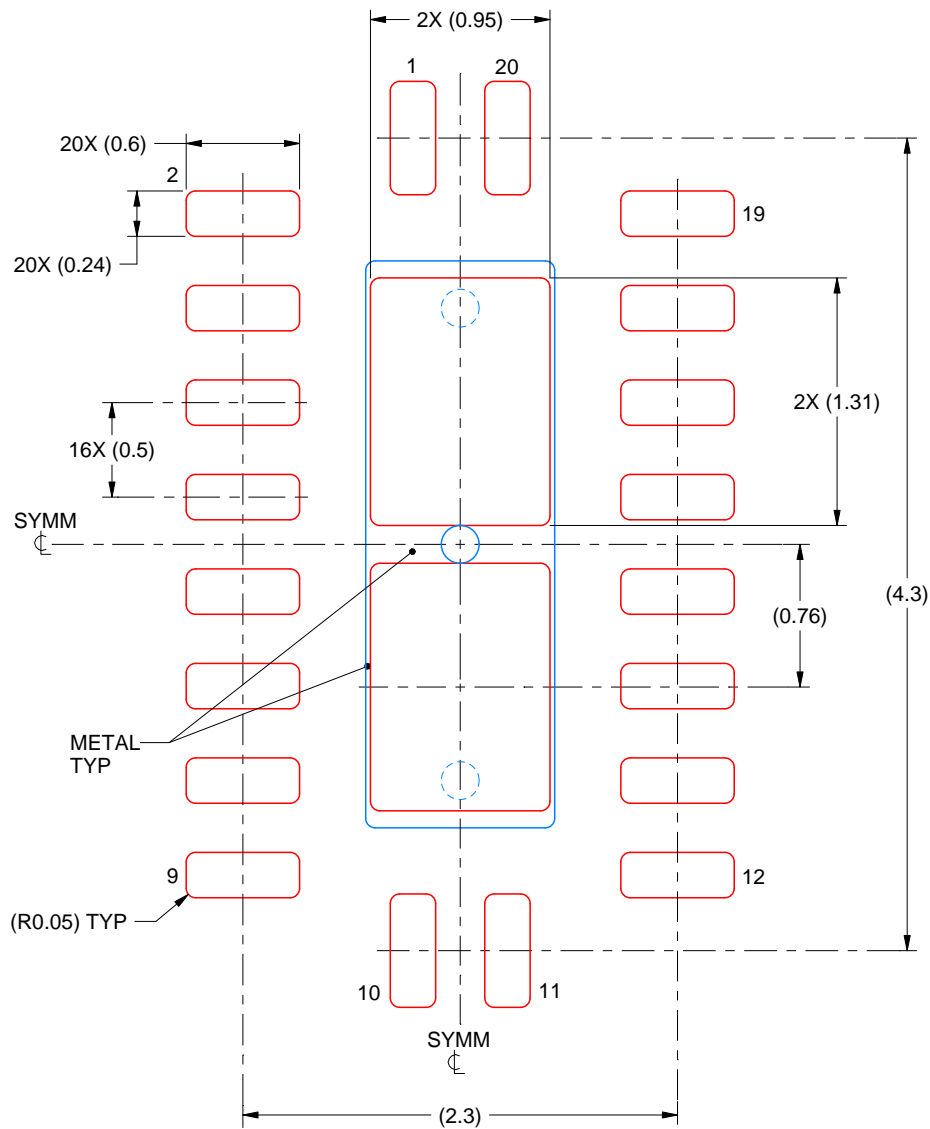


# EXAMPLE STENCIL DESIGN

RKS0020A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



**SOLDER PASTE EXAMPLE**  
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
 83% PRINTED SOLDER COVERAGE BY AREA  
 SCALE:25X

4222490/B 02/2021

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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